## NSN 5961-01-217-4121

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-217-4121 **Inclosure Material:** Metal **Overall Length:** 0.180 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 drain to gate voltage and 200.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 5.50 amperes source current and 22.00 amperes off-state current, peak **Power Rating Per Characteristic:** 25.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/557 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Mil-prf-19500 spec.

Mil-std (military Standard):

No Fiig: A110a0